

RN2971FE(TE85L,F)

RN2971FE(TE85L,F) Information

Numersener.com	RN2971FE(TE85L,F) Toshiba Semiconductor and Storage Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays, Pre-Biased TRANS 2PNP PREBIAS 0.1W ES6 SOT-563, SOT-666 For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

E-mail: salesdept@heisener.com



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



RN2971FE(TE85L,F) Specifications

Manufacturer Part Number	RN2971FE(TE85L,F)	
Manufacturer	Toshiba Semiconductor and Storage	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - Arrays, Pre-Biased	
Package	SOT-563, SOT-666	
Series	-	
Transistor Type	2 PNP - Pre-Biased (Dual)	
Current - Collector (Ic) (Max)	100mA	
Voltage - Collector Emitter Breakdown (Max)	50V	
Resistor - Base (R1) (Ohms)	10k	
Resistor - Emitter Base (R2) (Ohms)	_	
DC Current Gain (hFE) (Min) @ Ic, Vce	120 @ 1mA, 5V	
Vce Saturation (Max) @ Ib, Ic	300mV @ 250µA, 5mA	
Current - Collector Cutoff (Max)	100nA (ICBO)	
Frequency - Transition	200MHz	
Power - Max	100mW	
Mounting Type	Surface Mount	
Package / Case	SOT-563, SOT-666	
Supplier Device Package	ES6	
	Report errors?	

RN2971FE(TE85L,F) Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

RN2971FE(TE85L,F) Payment Methods





If you have any question about RN2971FE(TE85L,F), please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com